

International IR Rectifier

THYRISTOR/ DIODE and THYRISTOR/ THYRISTOR

Features

- High Voltage
- Industrial Standard Package
- Thick Al metal die and double stick bonding
- Thick copper baseplate
- UL E78996 approved
- 3500V_{RMS} isolating voltage

ADD-A-pak™ GEN V Power Modules

Benefits

- Up to 1600V
- Full compatible TO-240AA
- High Surge capability
- Easy Mounting on heatsink
- Al₂O₃ DBC insulator
- Heatsink grounded

45 A
60 A

Mechanical Description

The Generation V of Add-A-pak module combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid Copper baseplate at the bottom side of the device. The Cu baseplate allow an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improve thermal spread. The Generation V of AAP module is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other IR modules.

Electrical Description

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

Major Ratings and Characteristics

Parameters	IRK.41	IRK.56	Units
I _{T(AV)} or I _{F(AV)} @ 85°C	45	60	A
I _{O(RMS)} (*)	100	135	A
I _{TSM} @ 50Hz	850	1310	A
I _{FSM} @ 60Hz	890	1370	A
I ² t @ 50Hz	3.61	8.50	KA ² s
@ 60Hz	3.30	7.82	KA ² s
I ² /t	36.1	85.0	KA ² /s
V _{RRM} range	400 to 1600		V
T _{STG}	-40 to 125		°C
T _J	-40 to 125		°C

(*) As AC switch.



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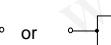
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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code -	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak reverse voltage V	V_{DRM} , max. repetitive peak off-state voltage, gate open circuit V	I_{RRM} I_{DRM} 125°C mA
IRK.41/.56	04	400	500	400	15
	06	600	700	600	
	08	800	900	800	
	10	1000	1100	1000	
	12	1200	1300	1200	
	14	1400	1500	1400	
	16	1600	1700	1600	

On-state Conduction

Parameters	IRK.41	IRK.56	Units	Conditions
$I_{T(AV)}$ Max. average on-state current (Thyristors)	45	60	A	180° conduction, half sine wave, $T_c = 85^\circ C$
$I_{F(AV)}$ Maximum average forward current (Diodes)	45	60		 or 
$I_{O(RMS)}$ Max. continuous RMS on-state current. As AC switch	100	135		t=10ms No voltage reapplied
I_{TSM} Max. peak, one cycle or non-repetitive on-state or I_{FSM} or forward current	850	1310		t=8.3ms Sinusoidal half wave, Initial $T_J = T_{J\max}$
	890	1370		t=10ms 100% V_{RRM} reapplied
	715	1100		t=8.3ms reapplied
	750	1150		t=10ms $T_J = 25^\circ C$,
	940	1450		t=8.3ms no voltage reapplied
	985	1520		
I^2t Max. I^2t for fusing	3.61	8.56	KA ² s	t=10ms No voltage reapplied
	3.30	7.82		t=8.3ms
	2.56	6.05		t=10ms 100% V_{RRM} reapplied
	2.33	5.53		t=8.3ms
	4.42	10.05		t=10ms $T_J = 25^\circ C$,
	4.03	9.60		t=8.3ms no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing (1)	36.1	85.6	KA ² s	t=0.1 to 10ms, no voltage reapplied
$V_{T(TO)}$ Max. value of threshold voltage (2)	0.88	0.85	V	Low level (3)
	0.91	0.88		High level (4)
r_t Max. value of on-state slope resistance (2)	5.90	3.53	mΩ	Low level (3)
	5.74	3.41		High level (4)
V_{TM} Max. peak on-state or V_{FM} forward voltage	1.81	1.54	V	$I_{TM} = \pi \times I_{T(AV)}$
				$I_{FM} = \pi \times I_{F(AV)}$
di/dt Max. non-repetitive rate of rise of turned on current	150		A/μs	$T_J = 25^\circ C$, from 0.67 V_{DRM} , $I_{TM} = \pi \times I_{T(AV)}$, $I_g = 500mA$, $t_r < 0.5 \mu s$, $t_p > 6 \mu s$
I_H Max. holding current	200		mA	$T_J = 25^\circ C$, anode supply = 6V, resistive load, gate open circuit
I_L Max. latching current	400			$T_J = 25^\circ C$, anode supply = 6V, resistive load

(1) I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

(2) Average power = $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$

(3) $16.7\% \times \pi \times I_{AV} < I < \pi \times I_{AV}$

(4) $I > \pi \times I_{AV}$

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Triggering

Parameters	IRK.41	IRK.56	Units	Conditions
P _{GM} Max. peak gate power	10	10	W	
P _{G(AV)} Max. average gate power	2.5	2.5		
I _{GM} Max. peak gate current	2.5	2.5	A	
-V _{GM} Max. peak negative gate voltage	10	4.0	V	T _J =-40°C T _J =25°C T _J =125°C
V _{GT} Max. gate voltage required to trigger		2.5		
		1.7		
I _{GT} Max. gate current required to trigger	270	mA	T _J =-40°C T _J =25°C T _J =125°C	Anode supply = 6V resistive load
	150			
	80			
V _{GD} Max. gate voltage that will not trigger	0.25	V		T _J =125°C, rated V _{DRM} applied
I _{GD} Max. gate current that will not trigger	6	mA		T _J =125°C, rated V _{DRM} applied

Blocking

Parameters	IRK.41	IRK.56	Units	Conditions
I _{RRM} Max. peak reverse and I _{DRM} off-state leakage current at V _{RRM} , V _{DRM}	15	mA		T _J =125 °C, gate open circuit
V _{INS} RMS isolation voltage				
dv/dt Max. critical rate of rise of off-state voltage (5)	2500 (1 min)	V		50 Hz, circuit to base, all terminals shorted
	3500 (1 sec)			
dv/dt	500	V/μs		T _J =125°C, linear to 0.67 V _{DRM} gate open circuit

(5) Available with dv/dt = 1000V/μs, to complete code add S90 i.e. IRKT41/16AS90.

Thermal and Mechanical Specifications

Parameters	IRK.41	IRK.56	Units	Conditions	
T _J Junction operating temperature range	- 40 to 125		°C		
T _{stg} Storage temp. range	- 40 to 125				
R _{thJC} Max. internal thermal resistance, junction to case	0.23	0.20	K/W	Per module, DC operation	
R _{thCS} Typical thermal resistance case to heatsink	0.1			Mounting surface flat, smooth and greased	
T Mounting torque ± 10% to heatsink	5	Nm		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound	
busbar	3				
wt Approximate weight	110(4)		gr (oz)		
Case style	TO-240AA		JEDEC		

ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sine half wave conduction					Rect. wave conduction					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.41	0.11	0.13	0.17	0.23	0.34	0.09	0.14	0.18	0.23	0.34	°C/W
IRK.56	0.09	0.11	0.13	0.18	0.27	0.07	0.11	0.14	0.19	0.28	

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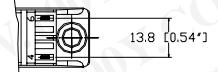
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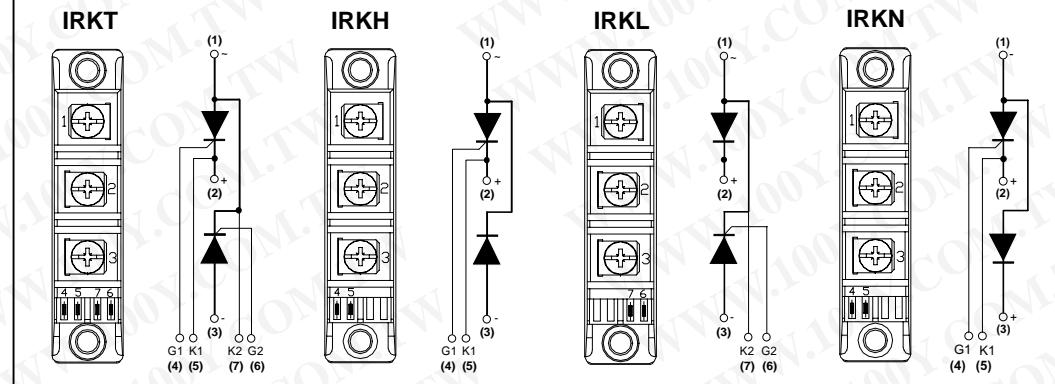
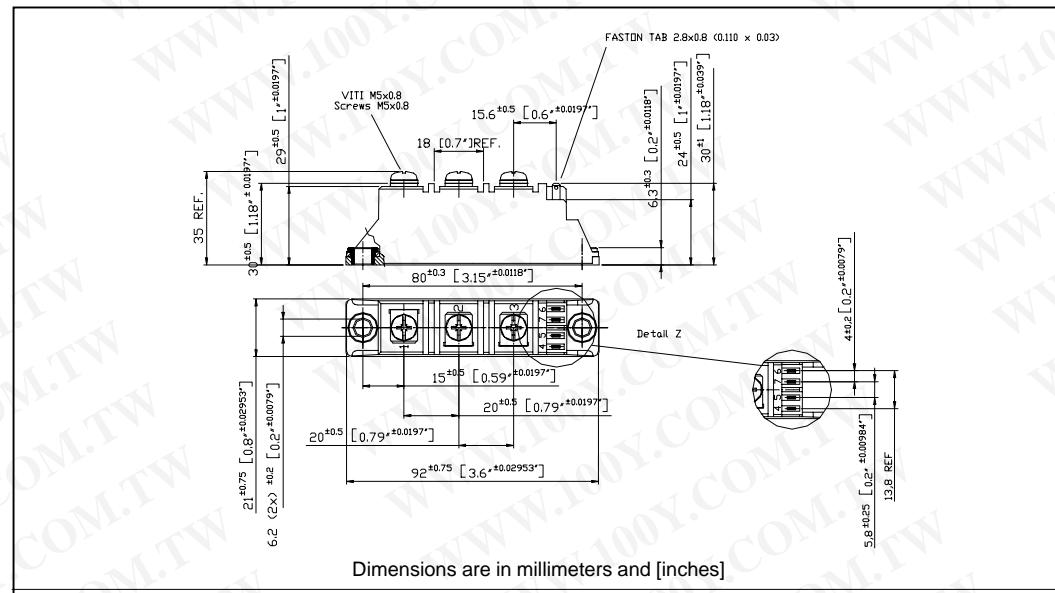
Ordering Information Table

Device Code		IRK	T	56	/	16	A	S90
1	-	Module type						
2	-	Circuit configuration (See Circuit Configuration table below)						
3	-	Current code **						
4	-	Voltage code (See Voltage Ratings table)						
5	-	A : Gen V						
6	-	dv/dt code: S90 = dv/dt 1000 V/μs						
No letter = dv/dt 500 V/μs								
** Available with no auxiliary cathode. To specify change: 41 to 42 56 to 57 e.g.: IRKT57/16A etc.								

IRK.57 types
 With no auxiliary cathode



Outline Table



NOTE: To order the Optional Hardware see Bulletin I27900

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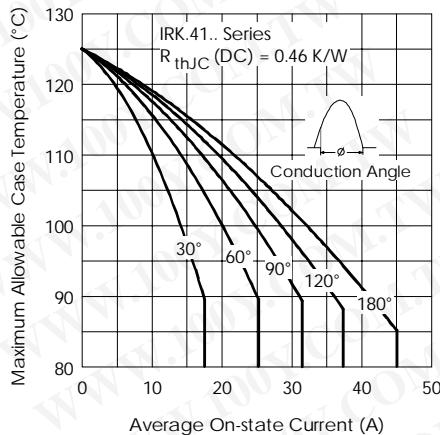


Fig. 1 - Current Ratings Characteristics

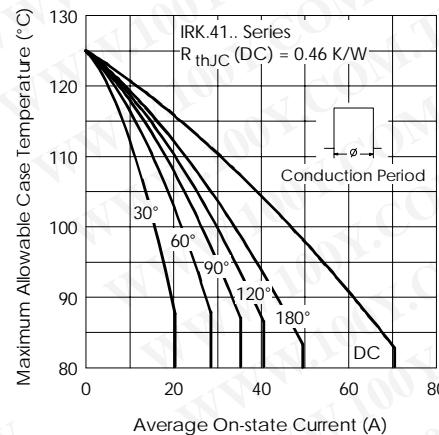


Fig. 2 - Current Ratings Characteristics

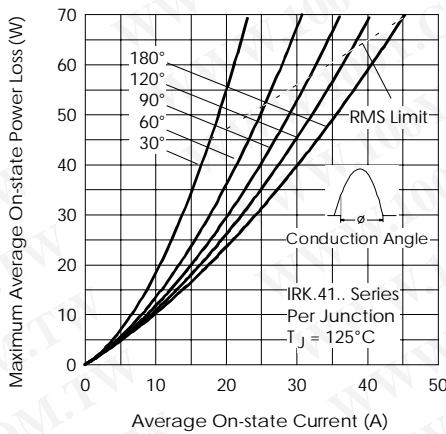


Fig. 3 - On-state Power Loss Characteristics

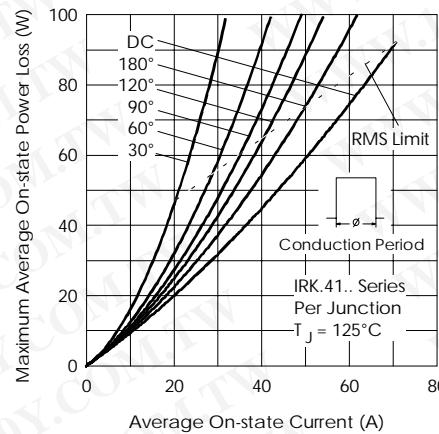


Fig. 4 - On-state Power Loss Characteristics

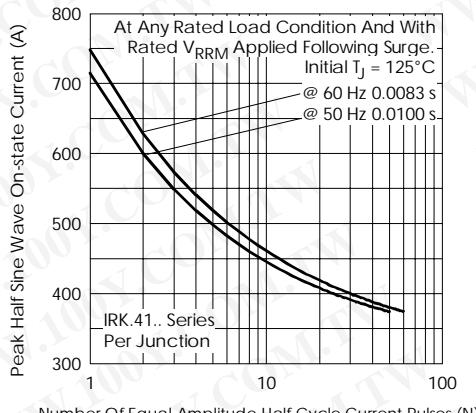


Fig. 5 - Maximum Non-Repetitive Surge Current

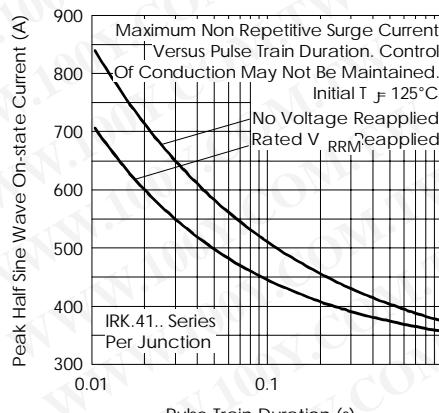


Fig. 6 - Maximum Non-Repetitive Surge Current

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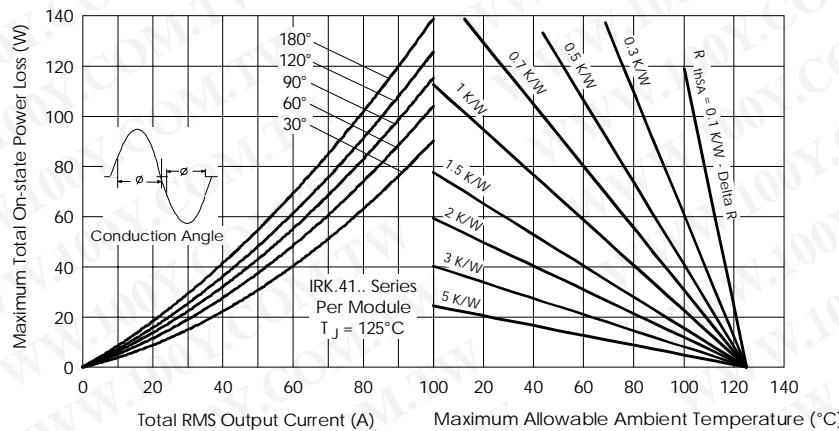


Fig. 7 - On-state Power Loss Characteristics

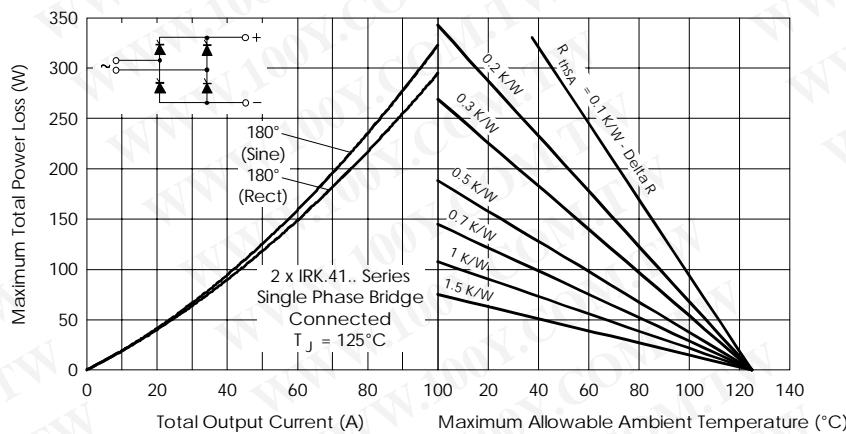


Fig. 8 - On-state Power Loss Characteristics

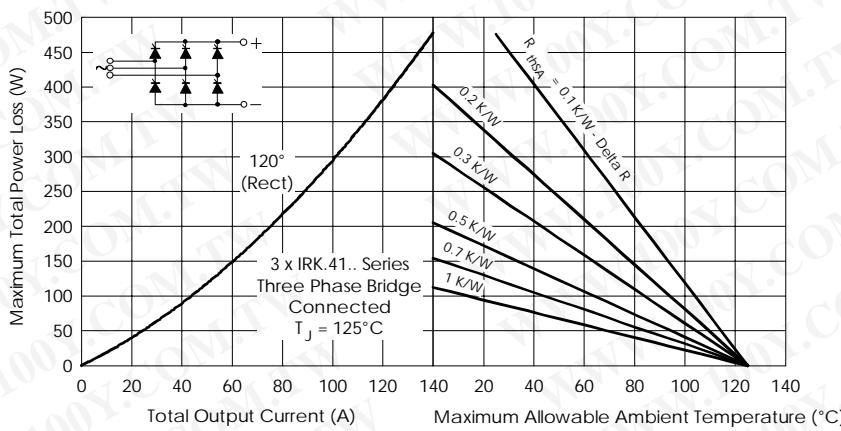


Fig. 9 - On-state Power Loss Characteristics

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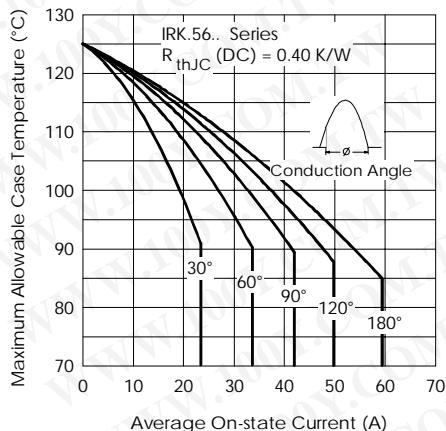


Fig. 10 - Current Ratings Characteristics

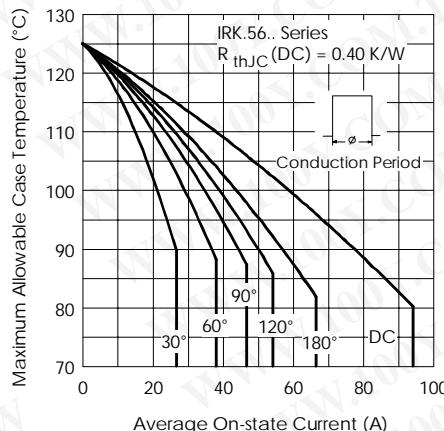


Fig. 11 - Current Ratings Characteristics

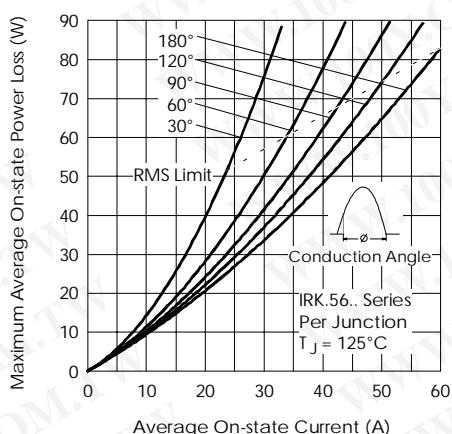


Fig. 12 - On-state Power Loss Characteristics

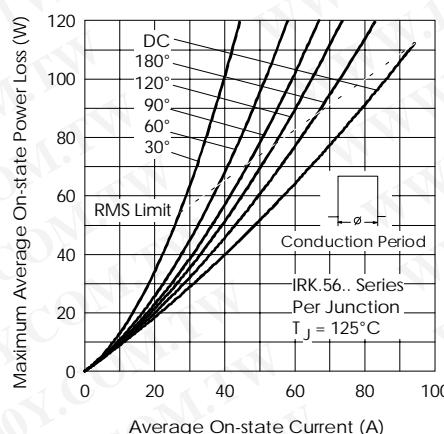


Fig. 13 - On-state Power Loss Characteristics

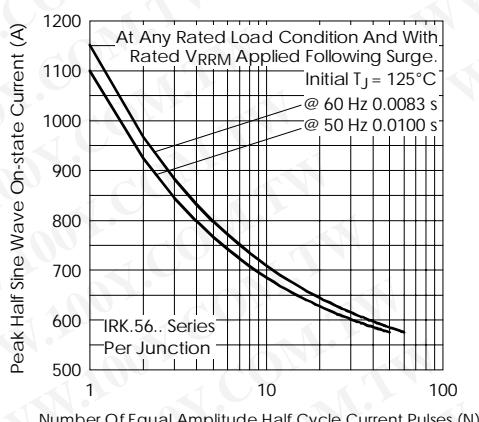


Fig. 14 - Maximum Non-Repetitive Surge Current

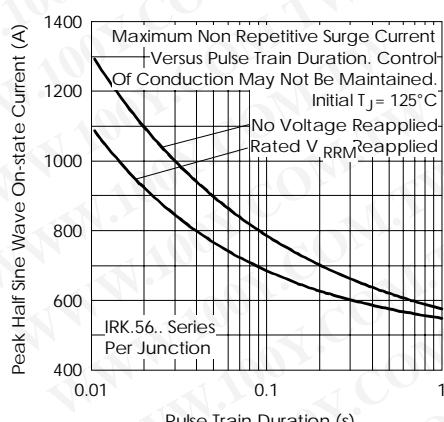


Fig. 15 - Maximum Non-Repetitive Surge Current

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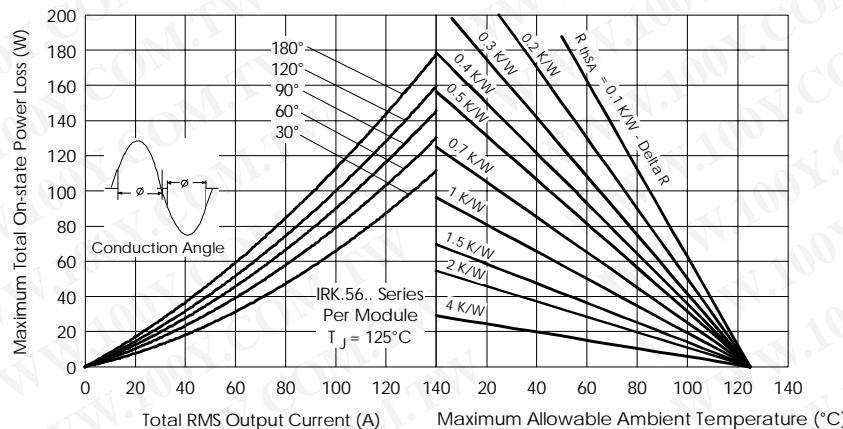


Fig. 16 - On-state Power Loss Characteristics

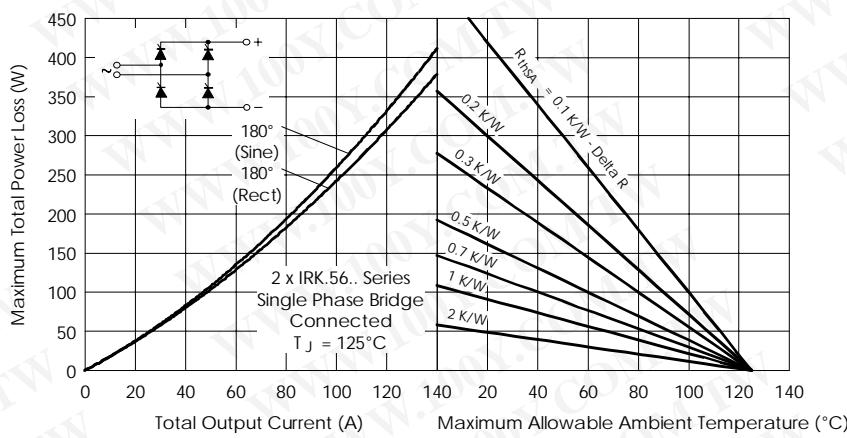


Fig. 17 - On-state Power Loss Characteristics

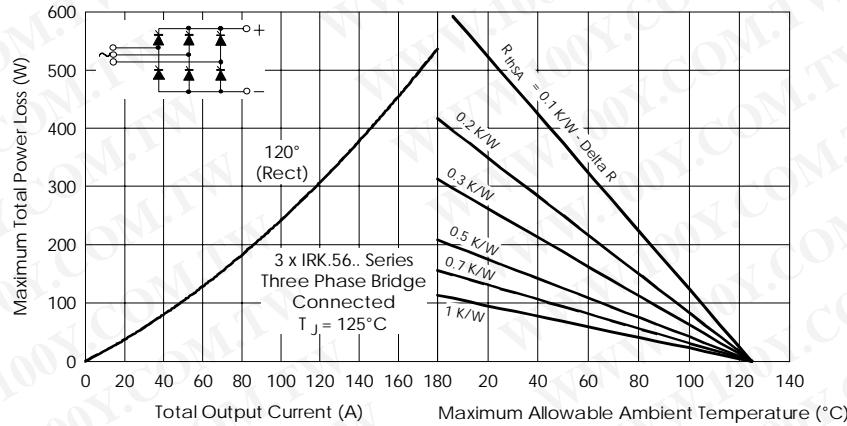


Fig. 18 - On-state Power Loss Characteristics

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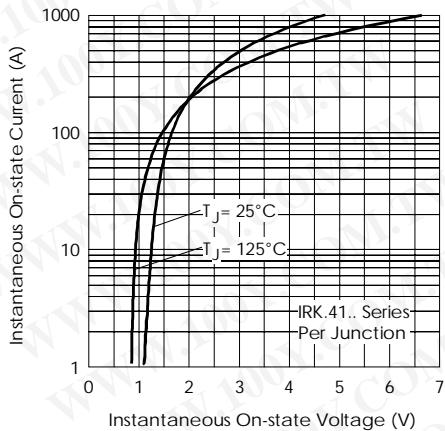


Fig. 19 - On-state Voltage Drop Characteristics

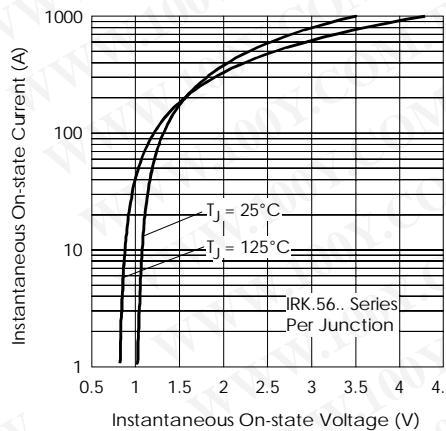


Fig. 20 - On-state Voltage Drop Characteristics

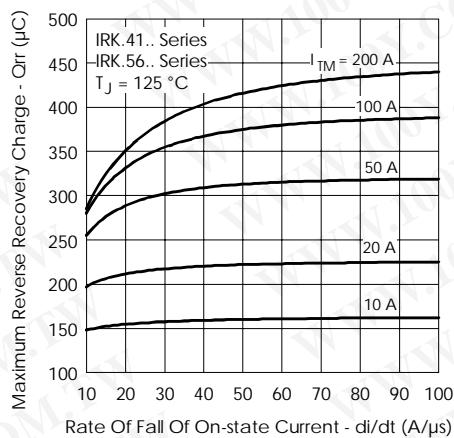


Fig. 21 - Recovery Charge Characteristics

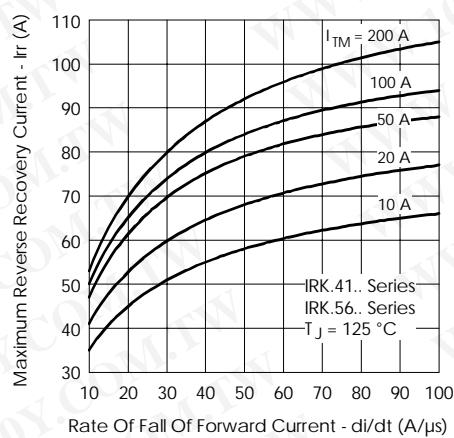


Fig. 22 - Recovery Current Characteristics

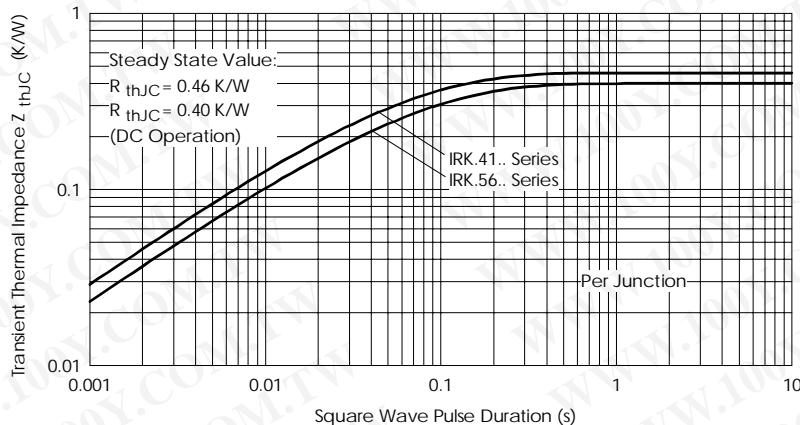


Fig. 23 - Thermal Impedance Z_{thJC} Characteristics

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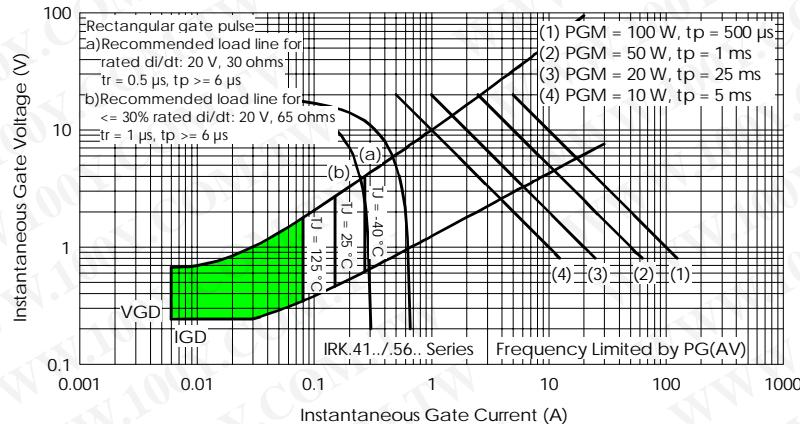


Fig. 24 - Gate Characteristics

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
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